

IFW



PATENT  
Customer No. 22,852  
Attorney Docket No. 03180.0326

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Write Application of:

Tadashi IGUCHI et al.

Application No.: 10/612,033

Filed: July 3, 2003

For: SEMICONDUCTOR MEMORY  
PREVENTING AN ELECTRIC  
SHORT CIRCUIT BETWEEN A  
WORD LINE AND A  
SEMICONDUCTOR SUBSTRATE,  
AND MANUFACTURING  
METHOD FOR THE  
SEMICONDUCTOR MEMORY (As  
Amended)

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)  
) Group Art Unit: 2826

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) Examiner: Quinto, Kevin V.  
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)  
) Confirmation No.: 5852

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

**AMENDMENT**

In reply to the Office Action mailed February 9, 2005, the period for response to which extends through May 9, 2005, Applicants submit the following amendments and remarks. This Amendment accompanies the filing of an Information Disclosure Statement.

**Amendments to the Claims** are reflected in the listing of claims beginning on page 2 of this paper.

**Remarks** begin on page 8 of this paper.